TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSⅢ)

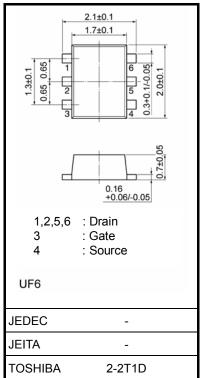
# SSM6J50TU

O High Current Switching Applications

- Compact package suitable for high-density mounting
- Low on-resistance:  $R_{on} = 205 m\Omega (max) (@V_{GS} = -2.0 V)$ 
  - $R_{on} = 100 m\Omega (max) (@V_{GS} = -2.5 V)$ Ron =
  - $64m\Omega$  (max) (@VGS = -4.5 V)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V <sub>DS</sub>	-20	V	
Gate-Source voltage		V <sub>GSS</sub>	±10	V	
Drain current	DC	I <sub>D</sub>	-2.5	Α	
	Pulse	I <sub>DP</sub>	-5	~	
Drain power dissipation		P <sub>D</sub> (Note 1)	500	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	



Weight: 7 mg (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

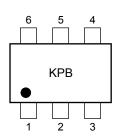
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

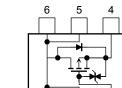
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board. (25.4 mm  $\times$  25.4 mm  $\times$  1.6 t, Cu Pad: 645 mm  $^2$  )

#### Marking

#### **Equivalent Circuit**





#### **Handling Precaution**

When handling individual devices that are not yet mounted on a circuit board, be sure that the environment is protected against electrostatic discharge. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Unit: mm

3

**Electrical Characteristics (Ta = 25°C)** 

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage curr	rent	I <sub>GSS</sub>	$V_{GS}=\pm 8~V,~V_{DS}=0$	_	_	±10	μA	
Drain-Source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0$	-20	_	_	v	
		V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = +10 \text{ V}$	-10	_	_		
Drain cut-off curre	ent	I <sub>DSS</sub>	$V_{DS} = -20 V, V_{GS} = 0$	_	_	-10	μA	
Gate threshold vo	Itage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.2 \text{ mA}$	-0.5	_	-1.2	V	
Forward transfer a	admittance	Y <sub>fs</sub>	$V_{DS} = -10 V, I_D = -1.5 A$ (Note2)	3.1	6.2	_	S	
Drain-Source on-resistance		R <sub>DS (ON)</sub>	$I_D = -1.5 \text{ A}, V_{GS} = -4.5 \text{ V}$ (Note2)	—	49	64	mΩ	
			$I_D = -1.5 \text{ A}, V_{GS} = -2.5 \text{ V}$ (Note2)	_	73	100		
			$I_D = -1.5 \text{ A}, V_{GS} = -2.0 \text{ V}$ (Note2)	_	105	205		
Input capacitance	acitance $C_{iss}$ $V_{DS} = -10 V$ , $V_{GS} = 0$ , f = 1 MHz		_	800	_	pF		
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	120	_	pF	
Output capacitance		C <sub>oss</sub>	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	—	160	_	pF	
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = -10 \text{ V}, \text{ I}_{D} = -1.5 \text{ A},$	—	15	_		
	Turn-off time	t <sub>off</sub>	$V_{GS} = 0 \sim -5 \text{ V}, \text{ R}_{G} = 4.7 \Omega$	—	51	—	ns	

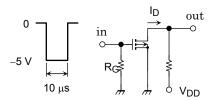
(b) V<sub>IN</sub>

(c) V<sub>OUT</sub>

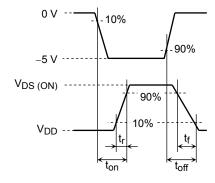
Note2: Pulse test

#### **Switching Time Test Circuit**

(a) Test Circuit



$$\begin{split} V_{DD} &= -10 \text{ V} \\ R_G &= 4.7 \ \Omega \\ D.U. &\leq 1\% \\ V_{IN} : t_r, t_f < 5 \text{ ns} \\ Common \text{ Source} \\ Ta &= 25^\circ\text{C} \end{split}$$



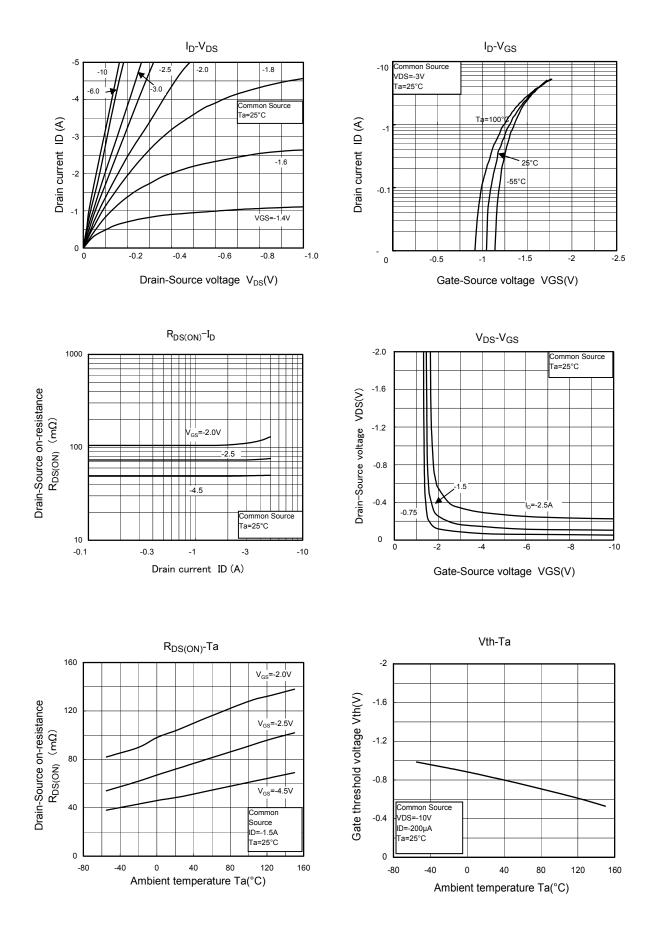
#### Precaution

 $V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is I<sub>D</sub>=-200  $\mu A$  for this product. For normal switching operation, V<sub>GS (on)</sub> requires a higher voltage than V<sub>th</sub> and V<sub>GS (off)</sub> requires a lower voltage than V<sub>th</sub>.

(The relationship can be established as follows:  $V_{GS (off)} < V_{th} < V_{GS (on)}$ )

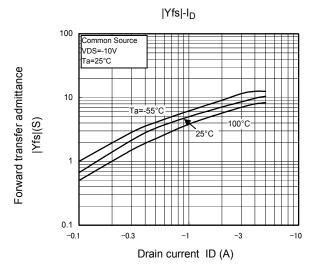
Be sure to take this into consideration when using the device.

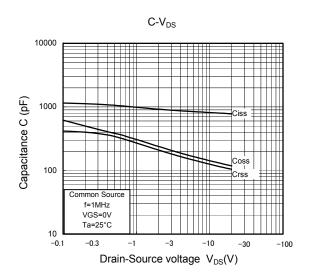
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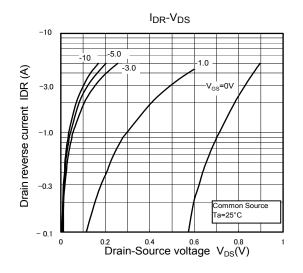


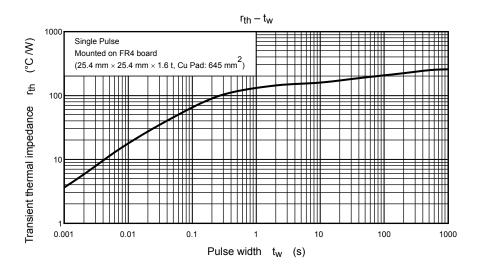
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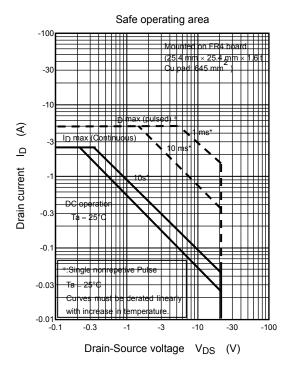
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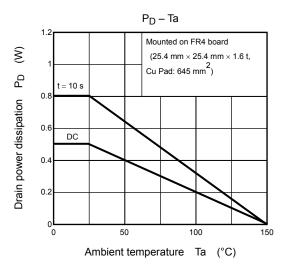












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